

## **ABSTRACT**

Disclosed is a solid-state image sensing device having at least one pixel. The pixel comprises a photoelectric conversion section for outputting an electric signal according to a quantity of incident light, and a sample hold circuit for sampling and holding the electric signal from the photoelectric conversion section and outputting the sampled and held electric signal as an image signal. In this device, a reset voltage for resetting the sample hold circuit obtains at least two different values.